



STB270N04 STB270N04-1 - STP270N04

N-CHANNEL 40V - 2.1mΩ - 160A - TO-220 - D²PAK - I²PAK
 STripFET™ Power MOSFET

General features

Type	V _{DSS}	R _{DS(on)}	I _D	P _{TOT}
STB270N04-1	40V	<2.9mΩ	120A	330W
STB270N04	40V	<2.5mΩ	160A	330W
STP270N04	40V	<2.9mΩ	120A	330W

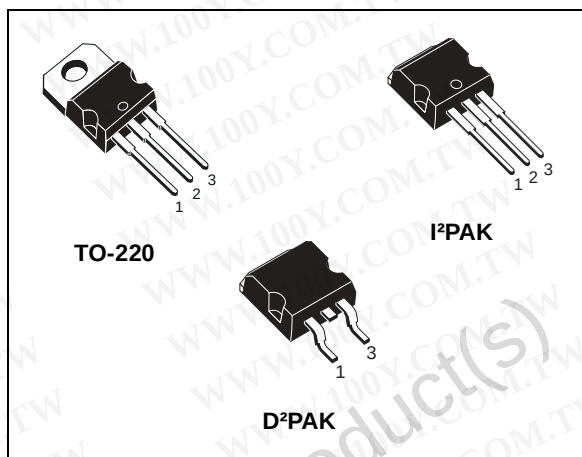
- 100% avalanche tested
- Standard threshold drive

Description

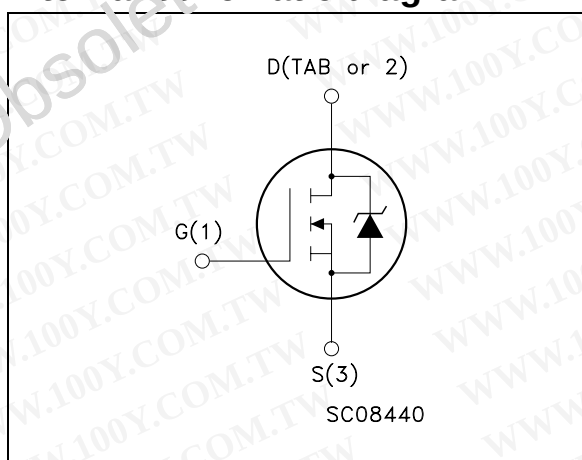
This N-Channel enhancement mode MOSFET is the latest refinement of STMicroelectronic unique "Single Feature Size™" strip-based process with less critical alignment steps and therefore a remarkable manufacturing reproducibility. The resulting transistor shows extremely high packing density for low on-resistance, rugged avalanche characteristics and low gate charge.

Applications

- High current, switching application
- Automotive



Internal schematic diagram



Order codes

Sales Type	Marking	Package	Packaging
STB270N04-1	B270N04	I ² PAK	TUBE
STB270N04	B270N04	D ² PAK	TAPE & REEL
STP270N04	P270N04	TO-220	TUBE

1 Electrical ratings

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Table 1. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		TO-220/I ² PAK	D ² PAK	
V _{DS}	Drain-Source Voltage (V _{GS} = 0)	40		V
V _{GS}	Gate-Source Voltage	± 20		V
I _D ⁽¹⁾	Drain Current (continuous) at T _C = 25°C	120	160	A
I _D ⁽¹⁾	Drain Current (continuous) at T _C =100°C	120	160	A
I _{DM} ⁽²⁾	Drain Current (pulsed)	480	640	A
P _{TOT}	Total Dissipation at T _C = 25°C	330		W
	Derating Factor	2.2		W/°C
dv/dt ⁽³⁾	Peak Diode Recovery voltage slope	3.5		V/ns
E _{AS} ⁽⁴⁾	Single Pulse Avalanche Energy	1		J
T _J T _{stg}	Operating Junction Temperature Storage Temperature	-55 to 175		°C

1. Current limited by package
2. Pulse width limited by safe operating area
3. I_{SD} ≤ 120A, di/dt ≤ 200A/μs, V_{DD} ≤ V_{(BR)DSS}, T_J ≤ T_{JMAX}
4. Starting T_J=25°C, I_d=80A, V_{dd}=32V

Table 2. Thermal data

Symbol	Parameter	Value		Unit
		TO-220/I ² PAK	D ² PAK	
R _{thj-case}	Thermal resistance junction-case Max	0.45		°C/W
R _{thj-pcb} ⁽¹⁾	Thermal resistance Junction-pcb Max	--	35	°C/W
R _{thj-a}	Thermal resistance junction-ambient Max	62.5	--	°C/W
T _I	Maximum lead temperature for soldering purpose (for 10 sec, 1.6mm from case)	300	--	°C

1. When mounted on 1inch² FR-4 board, 2 oz Cu.

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

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Table 3. On/off states

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V _{(BR)DSS}	Drain-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0	40			V
I _{DSS}	Zero Gate Voltage Drain Current (V _{GS} = 0)	V _{DS} = Max Rating, V _{DS} = MaxRating @125°C			10 100	μA μA
I _{GSS}	Gate Body Leakage Current (V _{DS} = 0)	V _{GS} = ±20V			±200	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	2		4	V
R _{DS(on)}	Static Drain-Source On Resistance	V _{GS} = 10V, I _D = 80A	TO-220 I ² PAK	2.5	2.9	mΩ
			D ² PAK	2.1	2.5	mΩ

Table 4. Dynamic

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
g _{fs} ⁽¹⁾	Forward Transconductance	V _{DS} = 15V, I _D = 80A		200		S
C _{iss}	Input Capacitance	V _{DS} = 25V, f = 1 MHz, V _{GS} = 0		7400		pF
C _{oss}	Output Capacitance			1800		pF
C _{rss}	Reverse Transfer Capacitance			47		pF
Q _g	Total Gate Charge	V _{DD} = 20V, I _D = 160A		110	150	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10V		27		nC
Q _{gd}	Gate-Drain Charge	(see Figure 2)		25		nC

1. Pulsed: pulse duration=300μs, duty cycle 1.5%

Table 5. Switching times

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ t_r	Turn-on Delay Time Rise Time	$V_{DD}=20\text{ V}$, $I_D=80\text{ A}$, $R_G=4.7\Omega$, $V_{GS}=10\text{ V}$ (see Figure 14)		22 180		ns ns
$t_{d(off)}$ t_f	Turn-off Delay Time Fall Time	$V_{DD}=20\text{ V}$, $I_D=80\text{ A}$, $R_G=4.7\Omega$, $V_{GS}=10\text{ V}$ (see Figure 14)		110 45		ns ns

Table 6. Source drain diode

Symbol	Parameter		Test Conditions	Min	Typ.	Max	Unit
I_{SD}	Source-drain Current	D ² PAK				160	A
		TO-220				120	A
		I ² PAK					
$I_{SDM}^{(1)}$	Source-drain Current (pulsed)	D ² PAK				640	A
		TO-220 I ² PAK				480	A
$V_{SD}^{(2)}$	Forward on Voltage		$I_{SD}=80\text{ A}$, $V_{GS}=0$			1.5	V
t_{rr}	Reverse Recovery Time		$I_{SD}=160\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $V_{DD}=32\text{ V}$, $T_j=150^\circ\text{C}$		70		ns
Q_{rr}	Reverse Recovery Charge				225		nC
I_{RRM}	Reverse Recovery Current				3.2		A

1. Pulse width limited by safe operating area
2. Pulsed: pulse duration=300 μs , duty cycle 1.5%

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2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

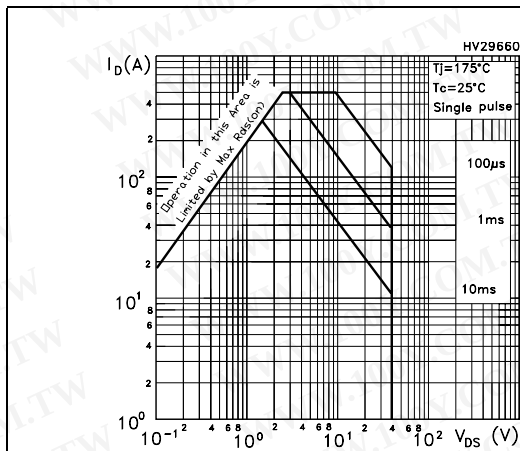


Figure 2. Thermal impedance

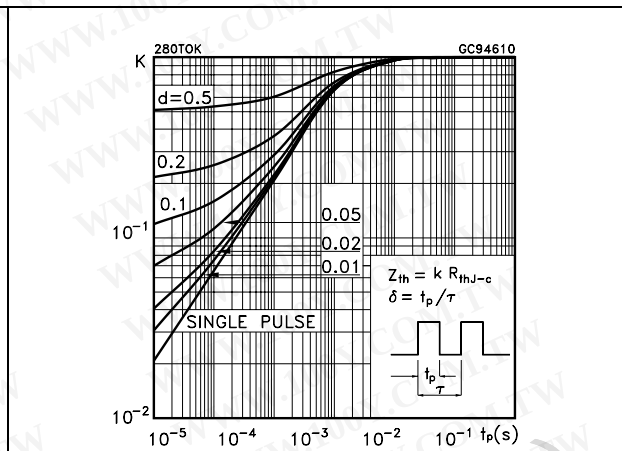


Figure 3. Output characteristics

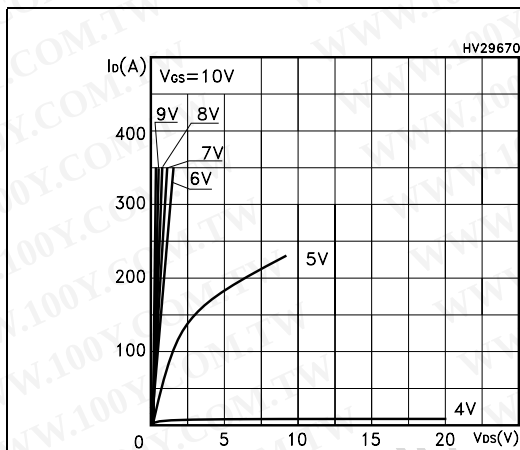


Figure 4. Transfer characteristics

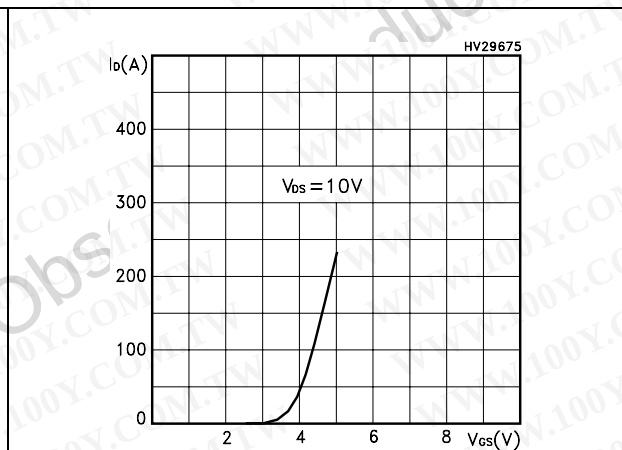


Figure 5. Static drain-source on resistance

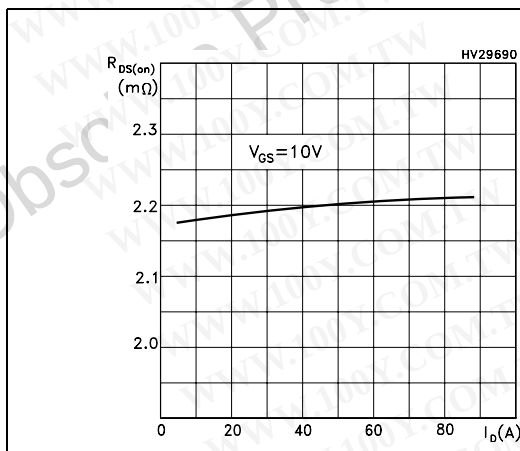


Figure 6. Normalized B_VDSS vs temperature

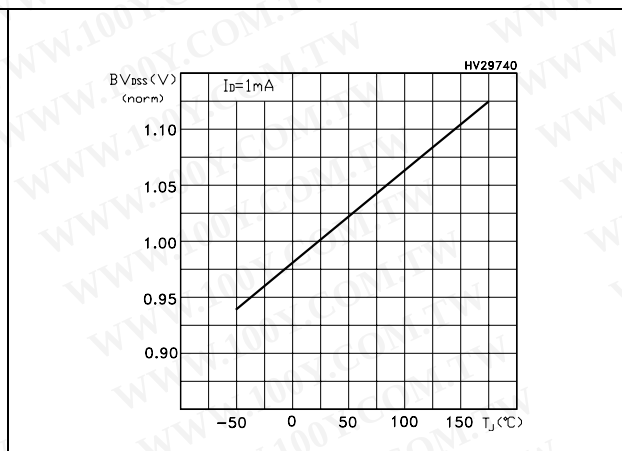


Figure 7. Gate charge vs gate-source voltage Figure 8. Capacitance variations

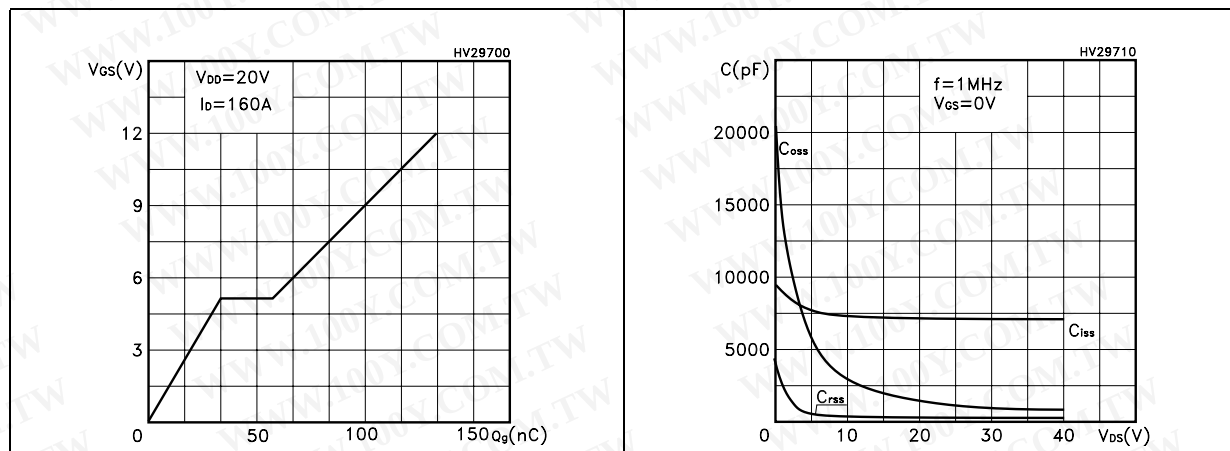


Figure 9. Normalized gate threshold voltage vs temperature

Figure 10. Normalized on resistance vs temperature

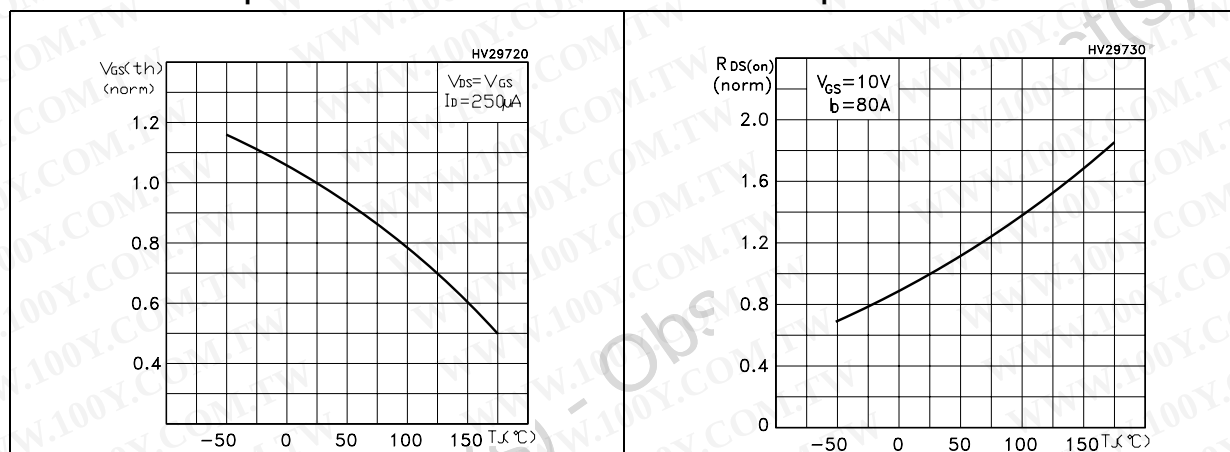
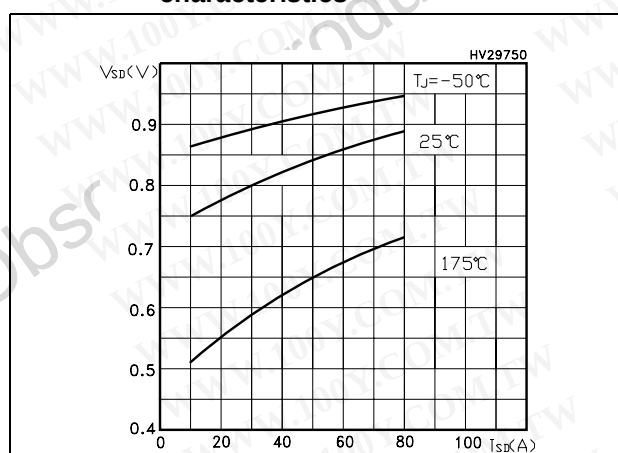


Figure 11. Source-drain diode forward characteristics



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3 Test circuit

Figure 12. Switching times test circuit for resistive load

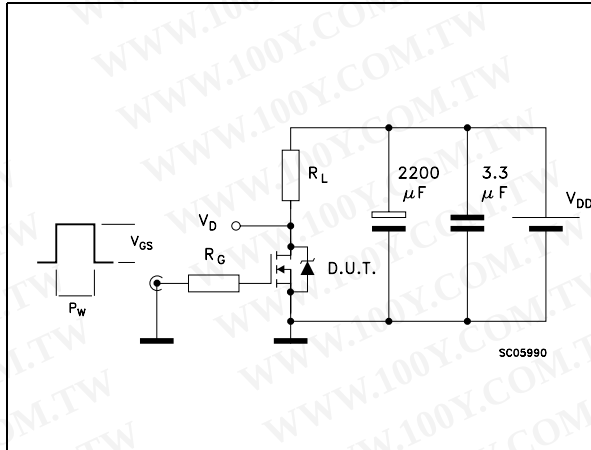


Figure 13. Gate charge test circuit

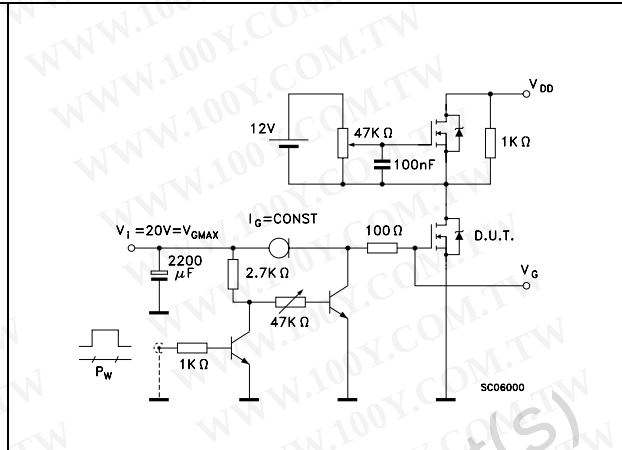


Figure 14. Test circuit for inductive load switching and diode recovery times

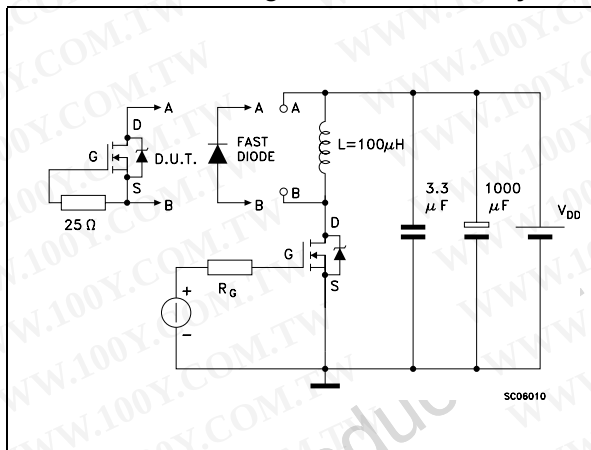


Figure 15. Unclamped Inductive load test circuit

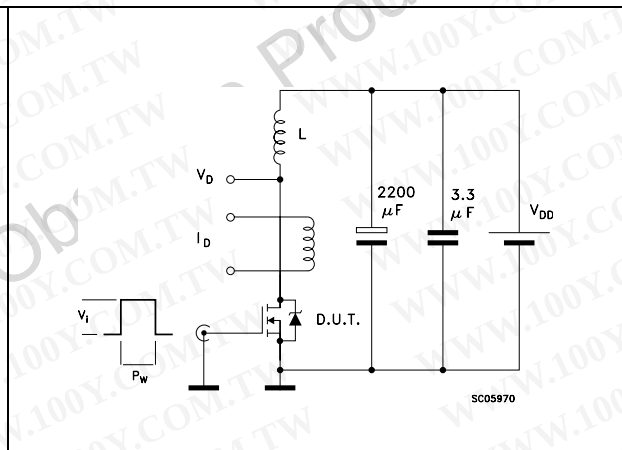


Figure 16. Unclamped inductive waveform

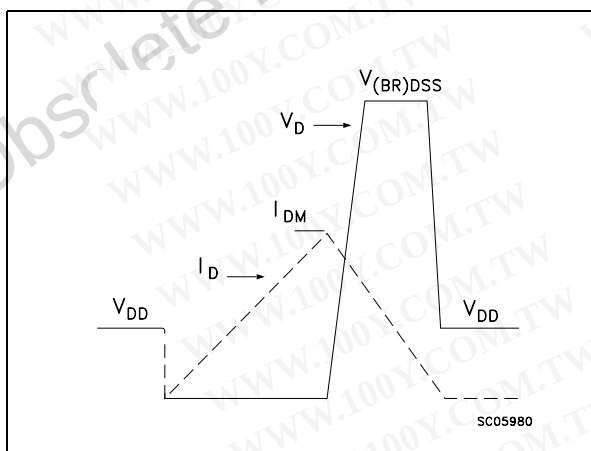
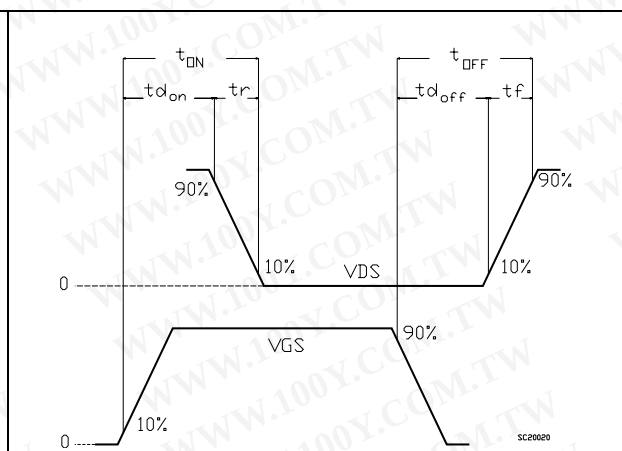


Figure 17. Switching time waveform



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

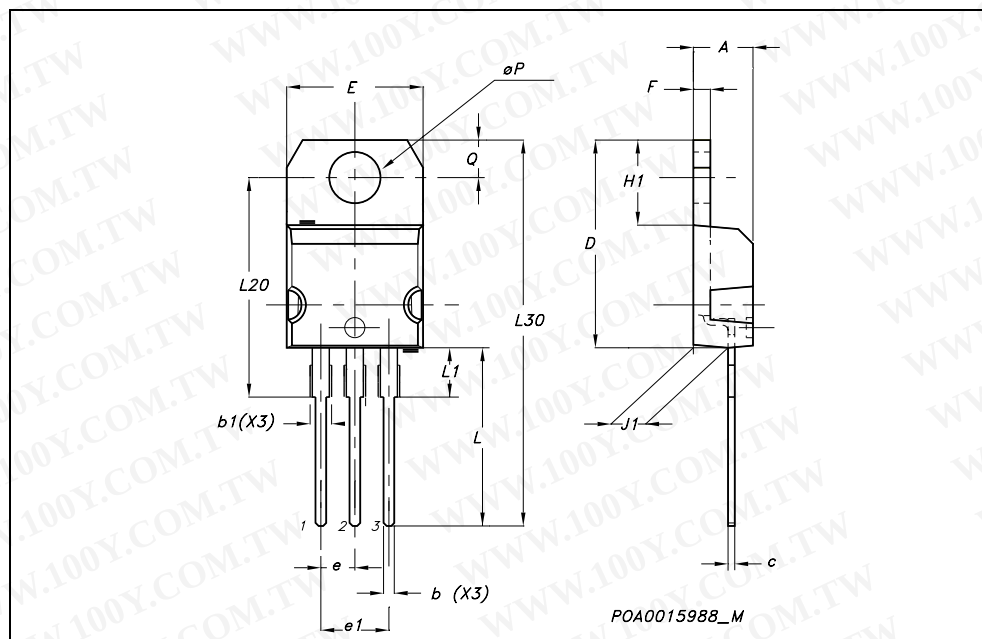
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TO-220 MECHANICAL DATA

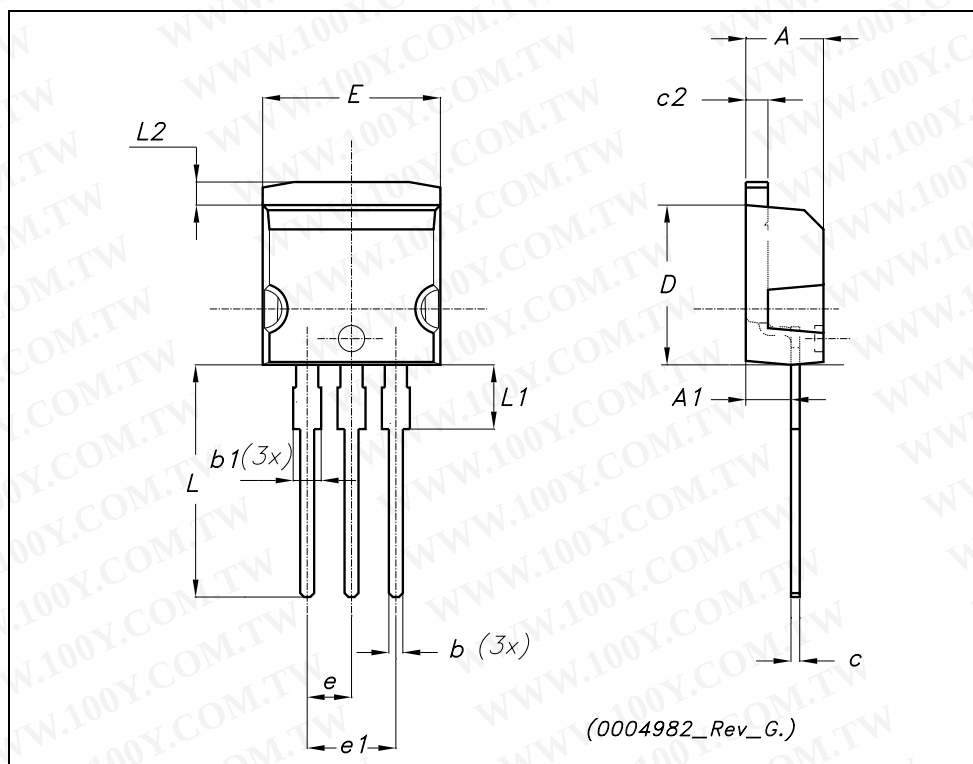
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.066
c	0.49		0.70	0.019		0.027
D	15.25		15.75	0.60		0.620
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
øP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



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TO-262 (I²PAK) MECHANICAL DATA

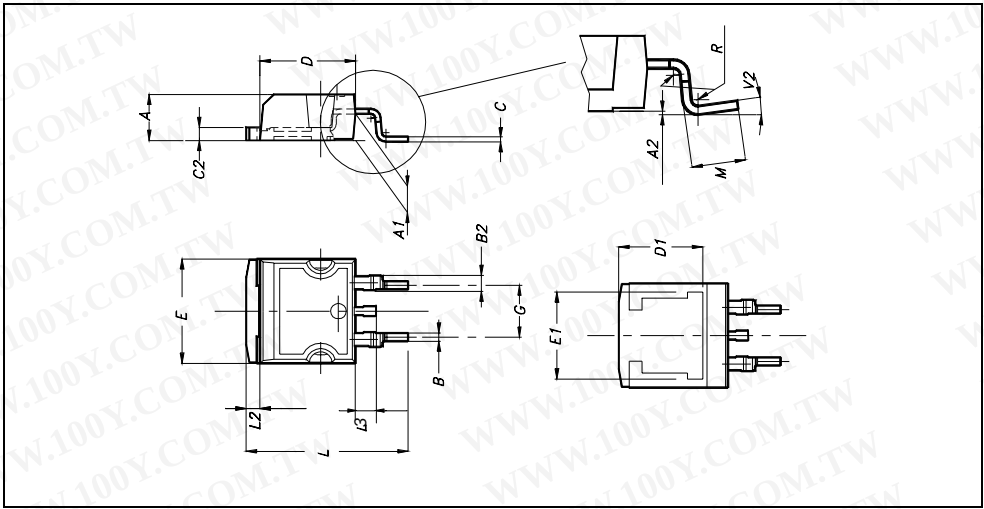
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352		0.368
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
E	10		10.40	0.393		0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055



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D²PAK MECHANICAL DATA

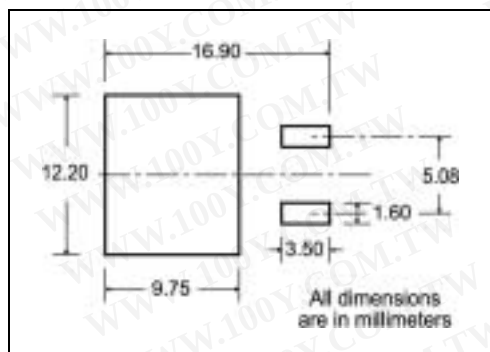
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.4		4.6	0.173		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.7		0.93	0.027		0.036
B2	1.14		1.7	0.044		0.067
C	0.45		0.6	0.017		0.023
C2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1		8			0.315	
E	10		10.4	0.393		
E1		8.5			0.334	
G	4.88		5.28	0.192		0.208
L	15		15.85	0.590		0.625
L2	1.27		1.4	0.050		0.055
L3	1.4		1.75	0.055		0.068
M	2.4		3.2	0.094		0.126
R		0.4			0.015	
V2	0°		4°			



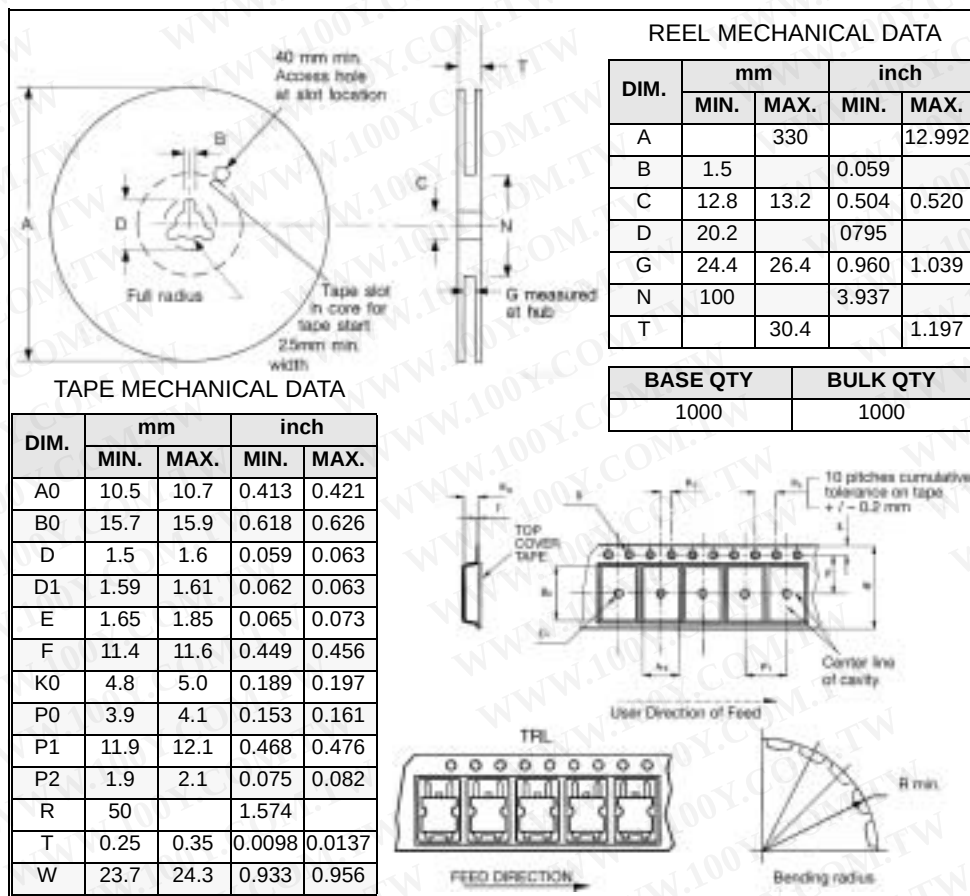
5 Packaging mechanical data

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D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



* on sales type

6 Revision history

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Table 7. Document revision history

Date	Revision	Changes
07-Oct-2005	1	Initial release.
10-Nov-2005	2	Preliminary version
09-Feb-2006	3	Complete datasheet

Obsolete Product(s) - Obsolete Product(s)

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